ISFET Sensors

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Message from the Guest Editor

This issue is devoted to the field effect structures for biosensing from the microscopic scale (EIS, ISFET) to the nanoscale (NanoFET) based on silicon nano/microtechnology or on organic nano/micro technology. Contributions on the integration of these field effect structures in lab-on-chips are of high interest for this special issue. All types of applications using field effect structures for on-line detection will be accepted.

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Special Issue

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Message from the Editor-in-Chief

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